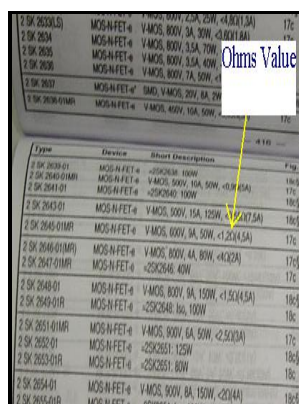


Power MOS FET - data book.

Toshiba Corporation - MOSFET as a Switch



Type	Device	Short Description	Pkg
2 SK 2030-01	MOS-N-FET-4	<2SK2030- 100W	18Q
2 SK 2040-01MR	MOS-N-FET-4	V-MOS, 800V, 15A, 50W, <100 (5A)	17C
2 SK 2041-01	MOS-N-FET-4	<2SK2040- 100W	18Q
2 SK 2043-01	MOS-N-FET-4	V-MOS, 500V, 15A, 125W, <15 (17.5A)	18Q
2 SK 2045-01MR	MOS-N-FET-4	V-MOS, 800V, 8A, 50W, <1.2 (1.5A)	17C
2 SK 2046-01MR	MOS-N-FET-4	V-MOS, 800V, 4A, 80W, <1.0 (1.2A)	17C
2 SK 2047-01MR	MOS-N-FET-4	<2SK2046- 80W	17C
2 SK 2049-01	MOS-N-FET-4	V-MOS, 800V, 8A, 150W, <1.5 (1.5A)	18Q
2 SK 2049-01R	MOS-N-FET-4	<2SK2049- 8A, 100W	18Q
2 SK 2051-01MR	MOS-N-FET-4	V-MOS, 800V, 8A, 50W, <2.5 (3.0A)	17C
2 SK 2052-01	MOS-N-FET-4	<2SK2051- 125W	18Q
2 SK 2053-01R	MOS-N-FET-4	<2SK2051- 80W	18Q
2 SK 2054-01	MOS-N-FET-4	V-MOS, 800V, 8A, 150W, <2.0 (1.4A)	18Q
2 SK 2055-01R	MOS-N-FET-4	<2SK2054- 8A, 100W	18Q

Description: -

-Power MOS FET - data book.

-Power MOS FET - data book.

Notes: Title from cover.

This edition was published in 1994



Filesize: 9.54 MB

Tags: #Mosfet #cross #reference

Power MOSFET

Complementary MOSFET Motor Controller The two MOSFETs are configured to produce a bi-directional switch from a dual supply with the motor connected between the common drain connection and ground reference. If you have the time, I would like to suggest to you that, find the right part number by yourself rather than depending on the transistor data book. What is the current that the lamp need in order to work? When high voltages are present, most of the applied voltage appears across the lightly doped N- layer.

Mosfet cross reference

I have a tricky problem, I want to charge 3 x lithium ion cells in parallel and connect the cells in series automatically when the equipment is turned on.

Power MOSFET » Electronics Notes

Upon checking the power side I found the same mosfet gave up again. P-channel MOSFET Switch But in some applications we require the use of P-channel enhancement-mode MOSFET were the load is connected directly to ground. The ohms value has to be as close as possible.

2N6901 Datasheet, Harris Semiconductor, Power N

For lower voltage devices, the doping levels for the P silicon areas and the N- become comparable and the voltage is shared across these two layers. These devices are the best choice for performance driven DC-DC converters. Only the positive +V DD supply rail is used to drive the motor.

Mosfet cross reference

Many power MOSFETs incorporate a vertical structure topology. .

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